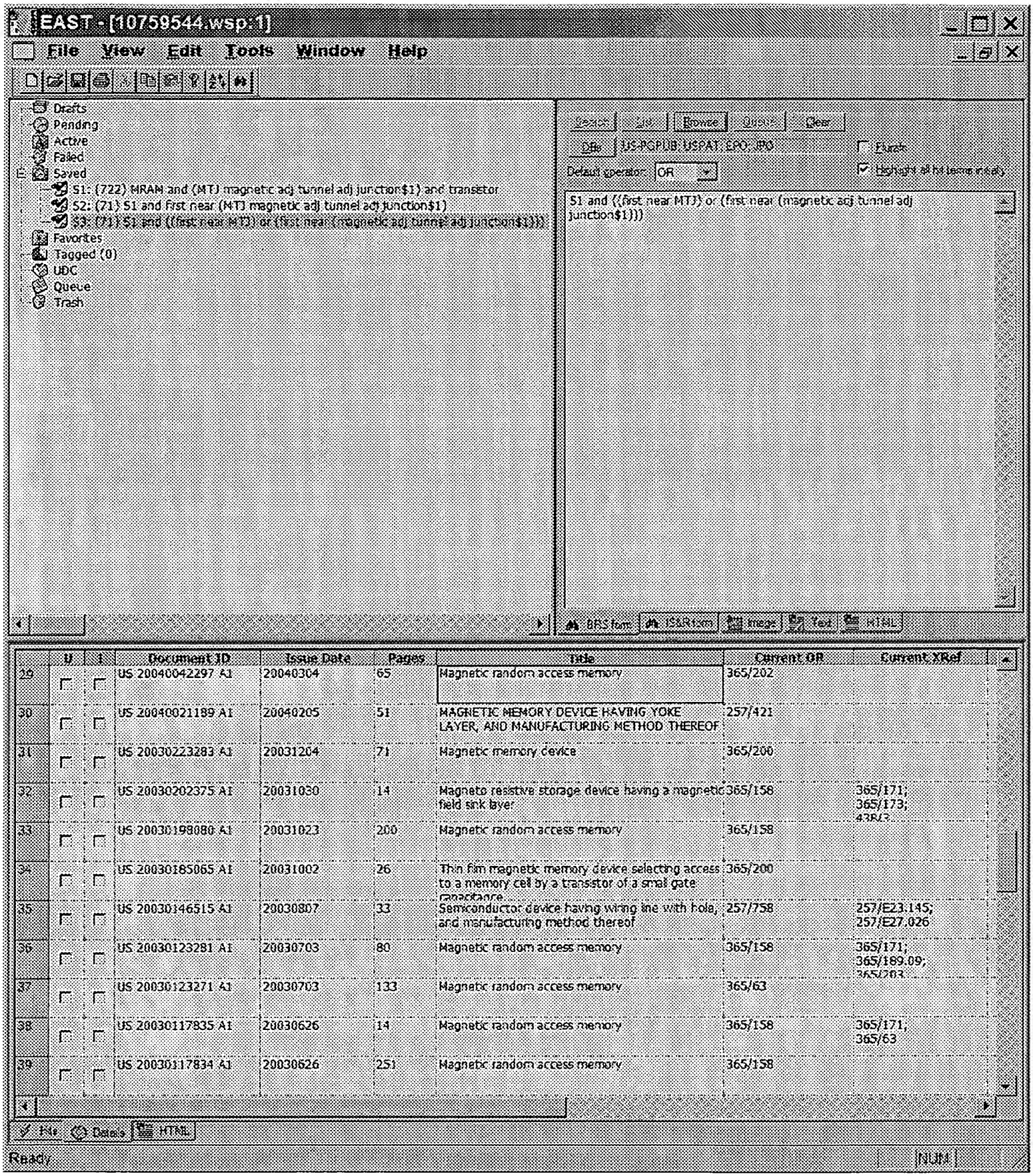

	U	I	Document ID	Issue Date	Pages	Title	Current OR	Current XRef
29			US 20040042297 A1	20040304	65	Magnetic random access memory	365/202	
30			US 20040021189 A1	20040205	51	MAGNETIC MEMORY DEVICE HAVING YOKE LAYER, AND MANUFACTURING METHOD THEREOF	257/421	
31			US 20030223283 A1	20031204	71	Magnetic memory device	365/200	
32			US 20030202375 A1	20031030	14	Magneto resistive storage device having a magnetic field sink layer	365/158	365/171; 365/173; 438/3
33			US 20030198080 A1	20031023	200	Magnetic random access memory	365/158	
34			US 20030185065 A1	20031002	26	Thin film magnetic memory device selecting access to a memory cell by a transistor of a small gate capacitance	365/200	
35			US 20030146515 A1	20030807	33	Semiconductor device having wiring line with hole, and manufacturing method thereof	257/758	257/E23.145; 257/E27.026
36			US 20030123281 A1	20030703	80	Magnetic random access memory	365/158	365/171; 365/189.09; 365/203
37			US 20030123271 A1	20030703	133	Magnetic random access memory	365/63	
38			US 20030117835 A1	20030626	14	Magnetic random access memory	365/158	365/171; 365/63
39			US 20030117834 A1	20030626	251	Magnetic random access memory	365/158	